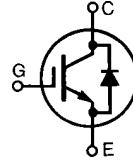


IGBT

Combi Pack

IXGA/IXGP12N100U1
IXGA/IXGP12N100AU1

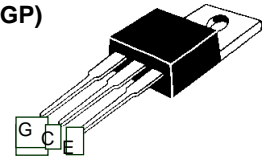
| V_{CES} | I_{C25} | $V_{CE(sat)}$ |
|-----------|-----------|---------------|
| 1000 V | 24 A | 3.5 V |
| 1000 V | 24 A | 4.0 V |



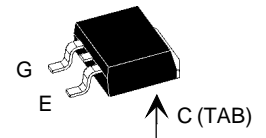
Preliminary Data Sheet

| Symbol | Test Conditions | Maximum Ratings | |
|---|---|----------------------------------|------------------|
| V_{CES} | $T_J = 25^\circ\text{C}$ to 150°C | 1000 | V |
| V_{CGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1\text{ M}\Omega$ | 1000 | V |
| V_{GES} | Continuous | ± 20 | V |
| V_{GEM} | Transient | ± 30 | V |
| I_{C25} | $T_C = 25^\circ\text{C}$ | 24 | A |
| I_{C90} | $T_C = 90^\circ\text{C}$ | 12 | A |
| I_{CM} | $T_C = 25^\circ\text{C}$, 1 ms | 48 | A |
| SSOA (RBSOA) | $V_{GE} = 15\text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 150\ \Omega$ Clamped inductive load, $L = 300\ \mu\text{H}$ | $I_{CM} = 24$ @ $0.8 V_{CES}$ | A |
| P_C | $T_C = 25^\circ\text{C}$ | 100 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| M_d | Mounting torque with screw M3 Mounting torque with screw M3.5 | 0.45/4 0.55/5 | Nm/lb.in. |
| Weight | | 4 | g |
| Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s | | 300 | $^\circ\text{C}$ |

TO-220AB(IXGP)



TO-263 AA (IXGA)



Features

- International standard packages JEDEC TO-220AB and TO-263AA
- IGBT with antiparallel FRED in one package
- Second generation HDMOS™ process
- Low $V_{CE(sat)}$
 - for minimum on-state conduction losses
- MOS Gate turn-on
 - drive simplicity
- Fast Recovery Expitaxial Diode (FRED)
 - soft recovery with low I_{RM}

Applications

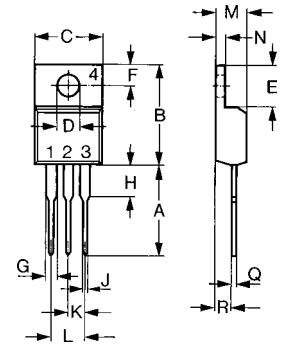
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

Advantages

- Easy to mount with one screw
- Space savings (two devices in one package)
- Reduces assembly time and cost
- High power density

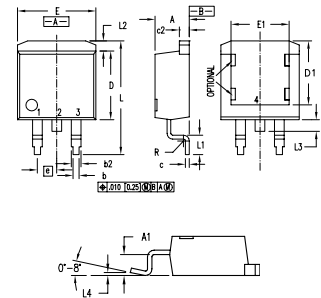
| Symbol | Test Conditions | Characteristic Values | | |
|---------------|---|---------------------------|------|---------------------|
| | | Min. | Typ. | Max. |
| BV_{CES} | $I_C = 3\text{ mA}$, $V_{GE} = 0\text{ V}$ | 1000 | | V |
| $V_{GE(th)}$ | $I_C = 250\ \mu\text{A}$, $V_{GE} = V_{GE}$ | 2.5 | | V |
| I_{CES} | $V_{CE} = 0.8$, V_{CES} $V_{GE} = 0\text{ V}$ | $T_J = 25^\circ\text{C}$ | | 300 μA |
| | | $T_J = 125^\circ\text{C}$ | | 3 mA |
| I_{GES} | $V_{CE} = 0\text{ V}$, $V_{GE} = \pm 20\text{ V}$ | | | $\pm 100\text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = I_{CE90}$, $V_{GE} = 15$ | 12N100 | | 3.5 V |
| | | 12N100A | | 4.0 V |

| Symbol | Test Conditions | Characteristic Values | | |
|--|---|-----------------------|------|------|
| | | Min. | Typ. | Max. |
| $(T_J = 25^\circ\text{C}, \text{ unless otherwise specified})$ | | | | |
| g_{fs} | $I_C = I_{C90}; V_{CE} = 10\text{ V},$ Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$ | 6 | 10 | S |
| Q_g | $I_C = I_{C90}; V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$ | | 65 | 90 |
| Q_{ge} | | | 8 | 20 |
| Q_{gc} | | | 24 | 45 |
| $t_{d(on)}$ | Inductive load, $T_J = 25^\circ\text{C}$ $I_C = I_{C90}, V_{GE} = 15\text{ V}, L = 300\ \mu\text{H}$ $V_{CE} = 800\text{ V}, R_G = R_{off} = 120\ \Omega$ Remarks: Switching times may increase for $V_{CE} (\text{Clamp}) > 0.8 V_{CES}$, higher T_J or increased R_G | | 100 | ns |
| t_{ri} | | | 200 | ns |
| $t_{d(off)}$ | | | 850 | 1000 |
| t_{fi} | | 12N100A | 500 | 700 |
| | | 12N100 | 800 | 1000 |
| E_{off} | | 12N100A | 4 | 6 |
| $t_{d(on)}$ | Inductive load, $T_J = 125^\circ\text{C}$ $I_C = I_{C90}, V_{GE} = 15\text{ V}, L = 300\ \mu\text{H}$ $V_{CE} = 800\text{ V}, R_G = R_{off} = 120\ \Omega$ Remarks: Switching times may increase for $V_{CE} (\text{Clamp}) > 0.8 V_{CES}$, higher T_J or increased R_G | | 100 | ns |
| t_{ri} | | | 200 | ns |
| E_{on} | | | 1.1 | mJ |
| $t_{d(off)}$ | | 12N100A | 900 | ns |
| t_{fi} | | 12N100 | 950 | ns |
| E_{off} | | 12N100A | 8 | mJ |
| | 12N100 | 10 | mJ | |
| R_{thJC} | | | 1.25 | K/W |
| R_{thCK} | | 0.25 | | K/W |

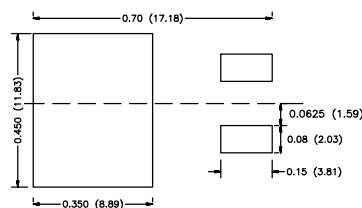
TO-220 AB (IXGP) Outline


| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 12.70 | 13.97 | 0.500 | 0.550 |
| B | 14.73 | 16.00 | 0.580 | 0.630 |
| C | 9.91 | 10.66 | 0.390 | 0.420 |
| D | 3.54 | 4.08 | 0.139 | 0.161 |
| E | 5.85 | 6.85 | 0.230 | 0.270 |
| F | 2.54 | 3.18 | 0.100 | 0.125 |
| G | 1.15 | 1.65 | 0.045 | 0.065 |
| H | 2.79 | 5.84 | 0.110 | 0.230 |
| J | 0.64 | 1.01 | 0.025 | 0.040 |
| K | 2.54 | BSC | 0.100 | BSC |
| M | 4.32 | 4.82 | 0.170 | 0.190 |
| N | 1.14 | 1.39 | 0.045 | 0.055 |
| Q | 0.35 | 0.56 | 0.014 | 0.022 |
| R | 2.29 | 2.79 | 0.090 | 0.110 |

| Reverse Diode (FRED) | | Characteristic Values | | |
|--|--|-----------------------|------|------|
| $(T_J = 25^\circ\text{C}, \text{ unless otherwise specified})$ | | | | |
| Symbol | Test Conditions | Min. | Typ. | Max. |
| V_F | $I_F = 8\text{ A}, V_{GE} = 0\text{ V},$ Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | | | 2.75 |
| I_{RM} | $I_F = I_{C90}, V_{GE} = 0\text{ V}, -di_F/dt = 100\text{ A}/\mu\text{s}$ | | 6.5 | A |
| t_{rr} | $V_R = 100\text{ V}, T_J = 125^\circ\text{C}$ $I_F = 1\text{ A}, -di/dt = 50\text{ A}/\mu\text{s}, V_R = 30\text{ V}, T_J = 25^\circ\text{C}$ | | 140 | ns |
| | | | 50 | 60 |
| R_{thJC} | | | | 2.5 |

TO-263 AA (IXGA) Outline


| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|------|
| | Min. | Max. | Min. | Max. |
| A | 4.06 | 4.83 | .160 | .190 |
| A1 | 2.03 | 2.79 | .080 | .110 |
| b | 0.51 | 0.99 | .020 | .039 |
| b2 | 1.14 | 1.40 | .045 | .055 |
| c | 0.46 | 0.74 | .018 | .029 |
| c2 | 1.14 | 1.40 | .045 | .055 |
| D | 8.64 | 9.65 | .340 | .380 |
| D1 | 7.11 | 8.13 | .280 | .320 |
| E | 9.65 | 10.29 | .380 | .405 |
| E1 | 6.86 | 8.13 | .270 | .320 |
| e | 2.54 | BSC | .100 | BSC |
| L | 14.61 | 15.88 | .575 | .625 |
| L1 | 2.29 | 2.79 | .090 | .110 |
| L2 | 1.02 | 1.40 | .040 | .055 |
| L3 | 1.27 | 1.78 | .050 | .070 |
| L4 | 0 | 0.38 | 0 | .015 |
| R | 0.46 | 0.74 | .018 | .029 |

Min. Recommended Footprint


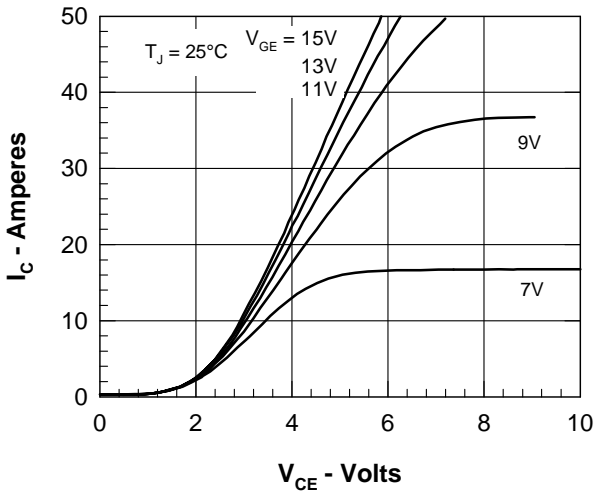


Figure 1. Saturation Voltage Characteristics

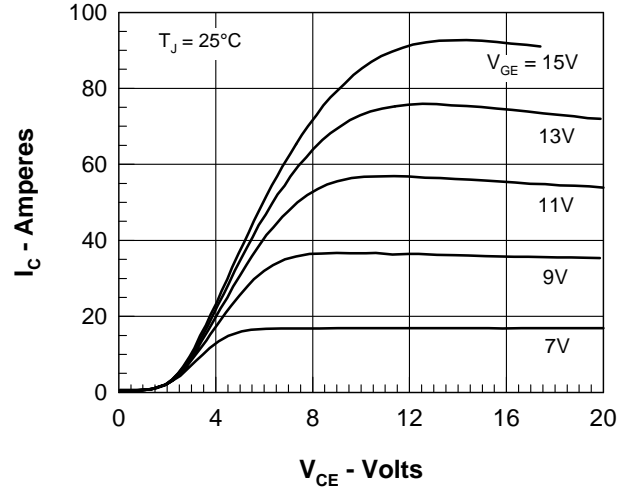


Figure 2. Extended Output Characteristics

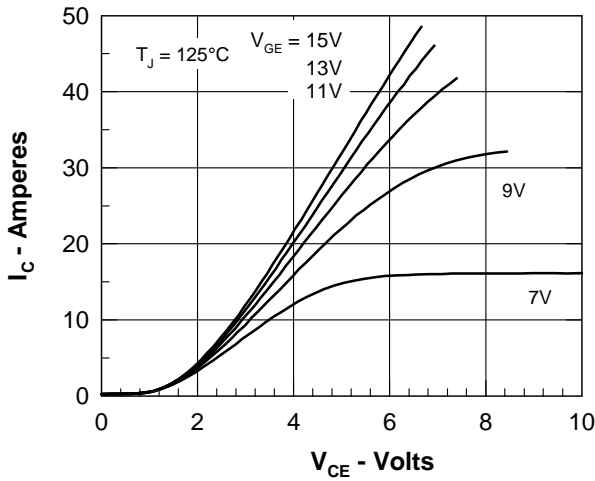


Figure 3. Saturation Voltage Characteristics

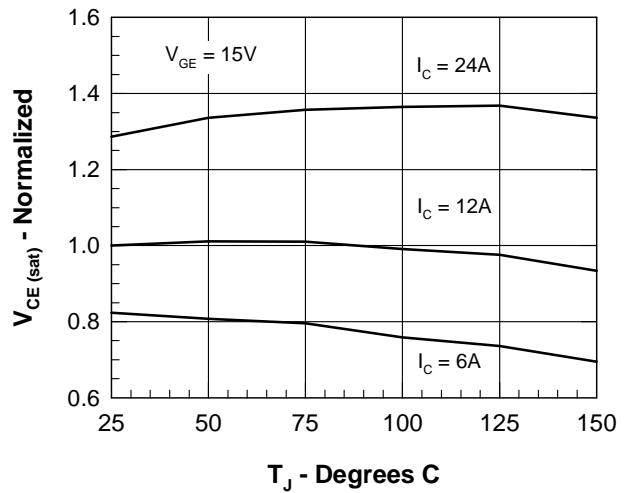


Figure 4. Temperature Dependence of $V_{CE(sat)}$

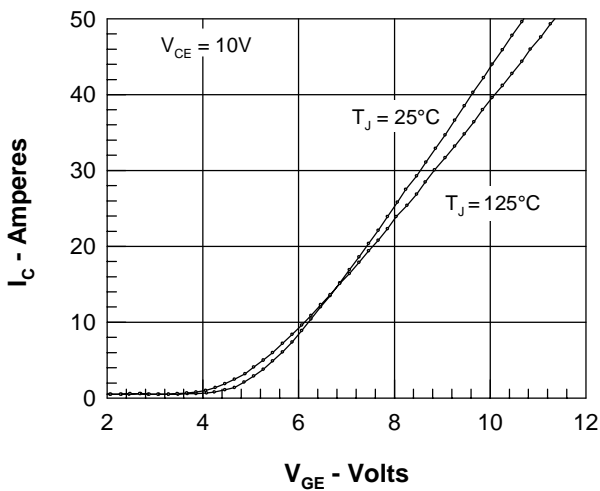


Figure 5. Admittance Curves

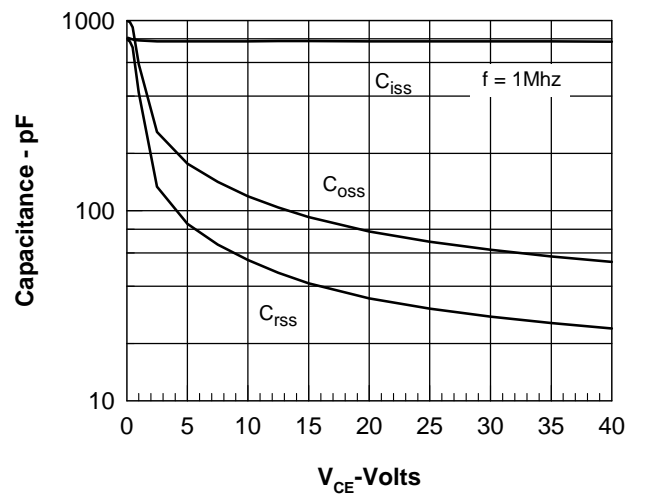


Figure 6. Capacitance Curves

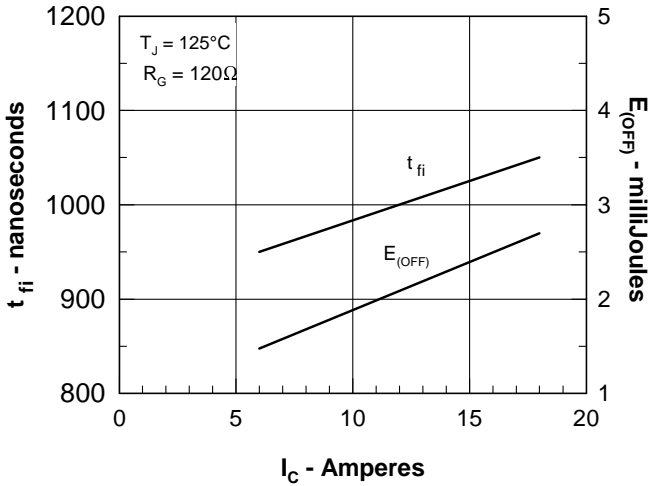


Figure 7. Dependence of t_{fi} and E_{OFF} on I_C .

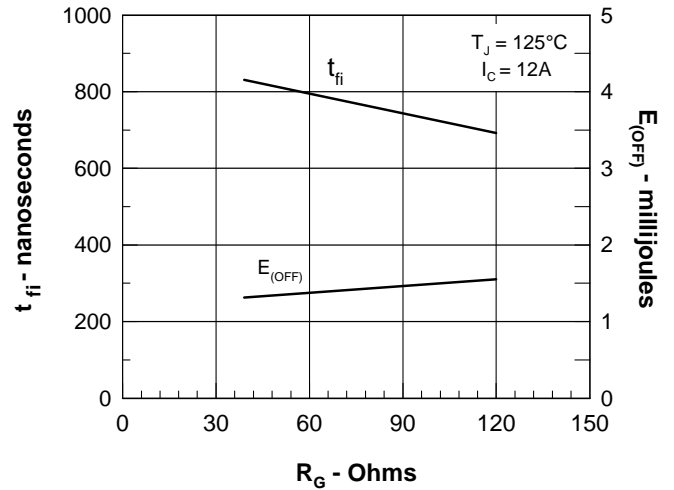


Figure 8. Dependence of t_{fi} and E_{OFF} on R_G .

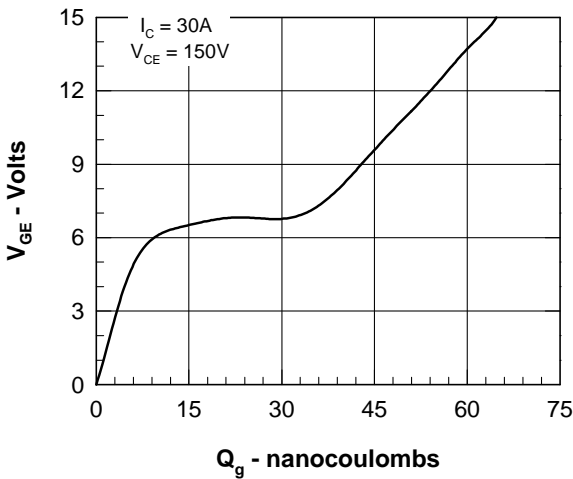


Figure 9. Gate Charge

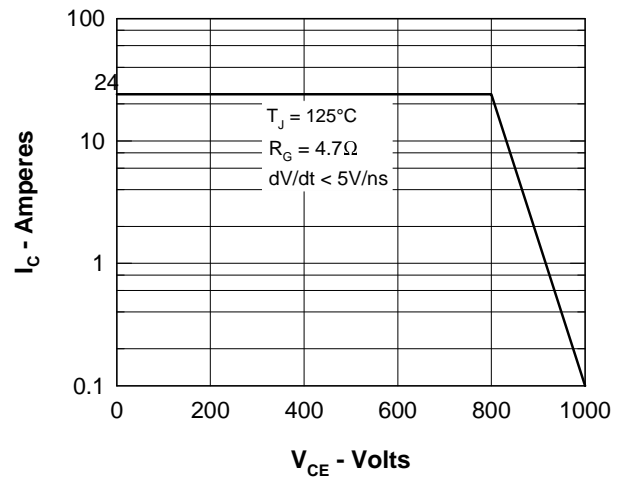


Figure 10. Turn-off Safe Operating Area

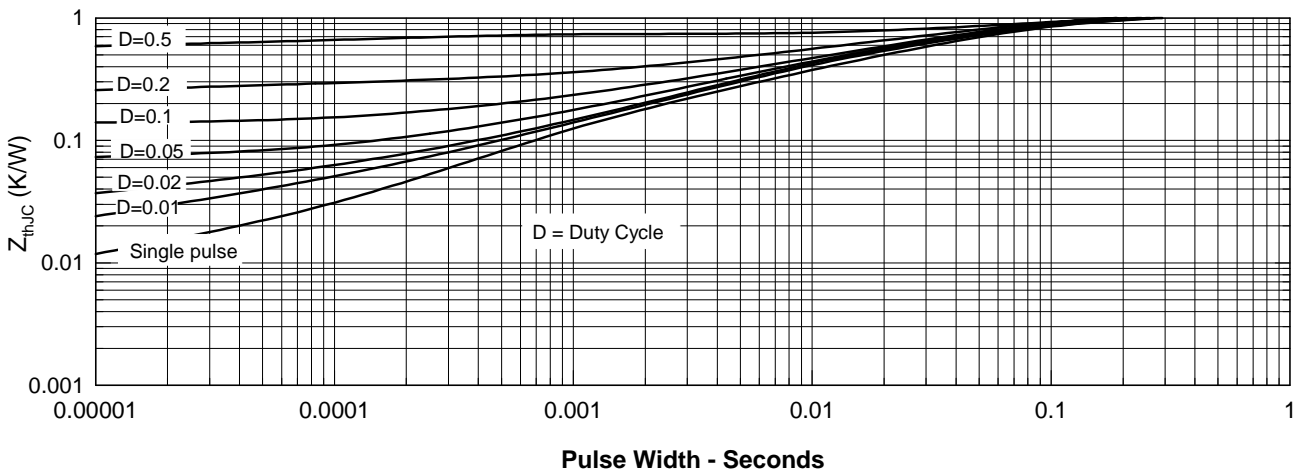


Figure 11. Transient Thermal Resistance



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